

MOSFET – Power, P-Channel Single ECH8

-30 V, -9 A, 17 m Ω

ECH8310

Features

- 4 V Drive
- Halogen free compliance
- Protection diode in
- This Device is Pb-Free, Halogen Free and RoHS Compliant

Specifications

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

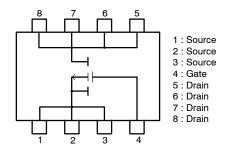
Symbol	Parameter	Conditions	Ratings	Unit
V _{DSS}	Drain-to-Source Voltage		-30	V
V _{GSS}	Gate-to-Source Voltage		±20	V
I _D	Drain Current (DC)		-9	Α
I _{DP}	Drain Current (Pulse)	PW ≤ 10 μs, duty cycle ≤ 1%	-60	Α
P _D	Allowable Power Dissipation	When mounted on ceramic substrate (900 mm ² X 0.8 mm)	1.5	W
Tch	Channel Temperature		150	°C
Tstg	Storage Temperature		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



SOT-28FL/ECH8 CASE 318BF

ELECTRICAL CONNECTION



MARKING DIAGRAM



ORDERING INFORMATION

Device	Package	Shipping [†]
ECH8310-TL-H	SOT-28FL ECH8 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

				Ratings		
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	Drain-to-Source Breakdown Voltage	$I_D = -1$ mA, $V_{GS} = 0$ V	-30	-	-	V
I _{DSS}	Zero-Gate Voltage Drain Current	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	-1	μΑ
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$		-	±10	μΑ
V _{GS(off)}	Cutoff Voltage	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$	-1.2	-	-2.6	V
yfs	Forward Transfer Admittance	$V_{DS} = -10 \text{ V}, I_D = -4.5 \text{ A}$		12	-	S
R _{DS(on)1}	Static Drain to Source	$I_D = -4.5 \text{ A}, V_{GS} = -10 \text{ V}$	9	13	17	mΩ
R _{DS(on)2}	On-State Resistance	$I_D = -2 \text{ A}, V_{GS} = -4.5 \text{ V}$	12	20	28	mΩ
R _{DS(on)3}	1	$I_D = -2 \text{ A}, V_{GS} = -4.0 \text{ V}$	13.5	23	32.5	mΩ
Ciss	Input Capacitance	V _{DS} = -10 V, f = 1 MHz	-	1400	-	pF
Coss	Output Capacitance	7	-	350	-	pF
Crss	Reverse Transfer Capacitance	7	-	250	-	pF
t _{d(on)}	Turn-ON Delay Time	See specified Test Circuit.	-	10	-	ns
t _r	Rise Time	7	-	45	-	ns
t _{d(off)}	Turn-OFF Delay Time	7	-	134	-	ns
t _f	Fall Time	7	-	87	-	ns
Qg	Total Gate Charge	$V_{DS} = -15 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -9 \text{ A}$	-	28	-	nC
Qgs	Gate-to-Source Charge	7	_	4	-	nC
Qgd	Gate-to-Drain "Miller" Charge	7	_	6	-	nC
V _{SD}	Diode Forward Voltage	I _S = -9 A, V _{GS} = 0 V	_	-0.8	-1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

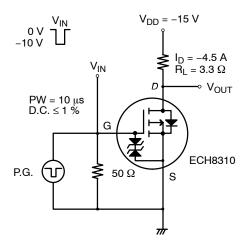
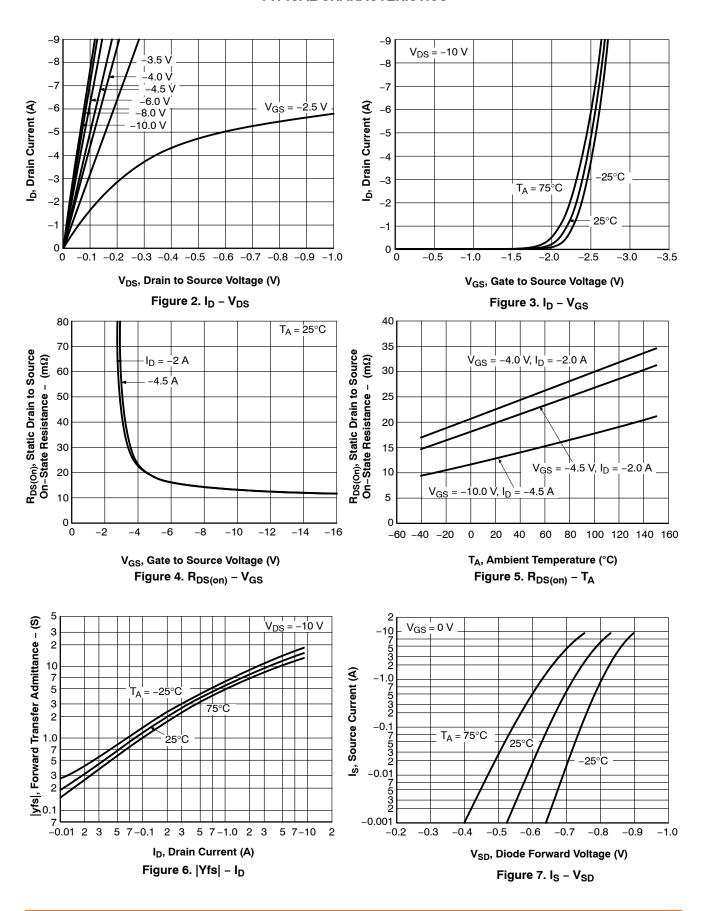


Figure 1. Switching Time Test Circuit

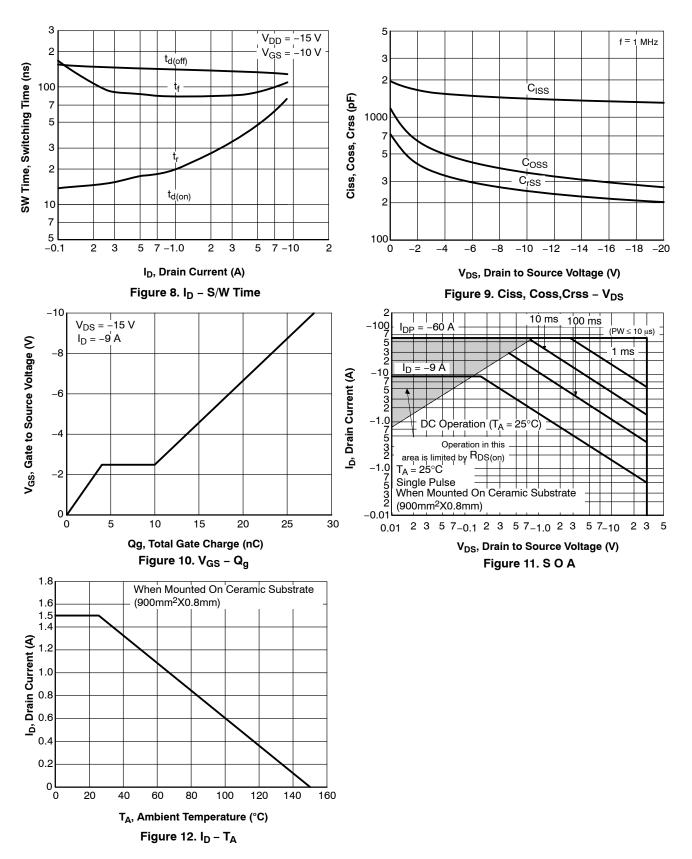
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TYPICAL CHARACTERISTICS



ECH8310

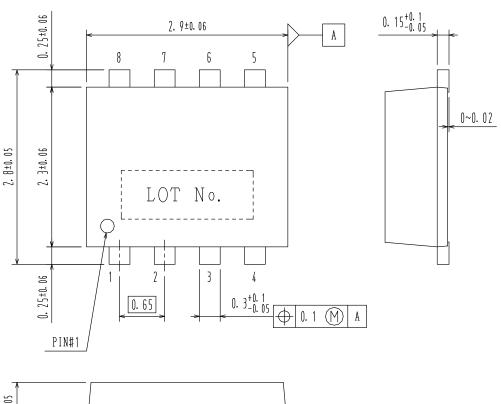
TYPICAL CHARACTERISTICS (CONTINUED)

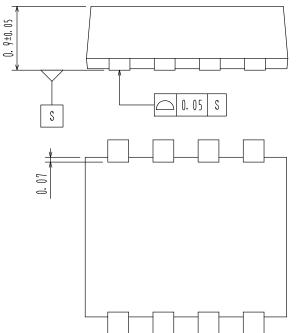


Note on usage: Since the ECH8310 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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DATE 31 MAR 2012





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